## NSN 5961-01-228-3091

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View Online at https://aerobasegroup.com/nsn/5961-01-228-3091 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.380 inches **Overall Width:** 1.050 inches **Function For Which Designed:** Voltage regulator **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-3 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 6.8 regulator voltage **Current Rating Per Characteristic:** 1.85 milliamperes source cutoff current horsepower metric **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Nuclear hardness critical item; junction pattern arrangement: pn **Nuclear Hardness Critical Feature:** Hardened **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

No

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